QUADRUPOLE MASS SPECTROMETRY CHARACTERIZATION OF LOW PRESSURE MICROWAVE PLASMAS FOR ATOMIC SPECIES PRODUCTION

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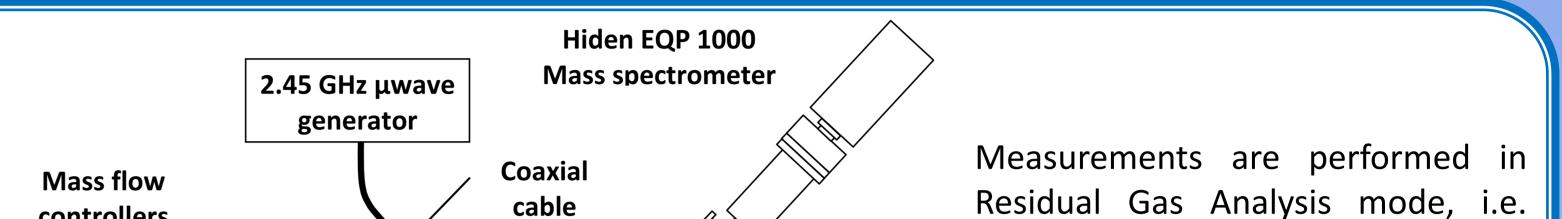
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Introduction

1. Experimental setup

Interaction of atomic species on surfaces is of primary importance to better control surface treatments assisted by remote plasmas. However, up to now, many attempts have been done to define these phenomena qualitatively and, to a lesser extent, quantitatively. For example, by looking at the



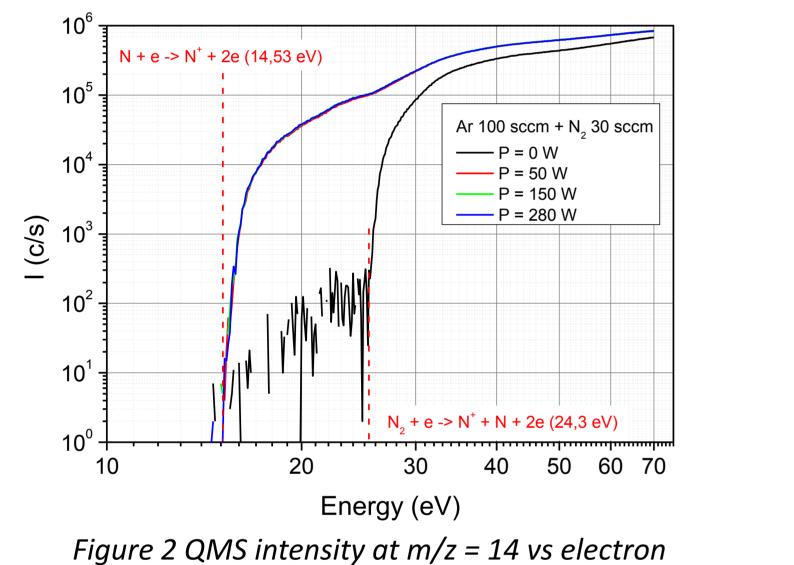


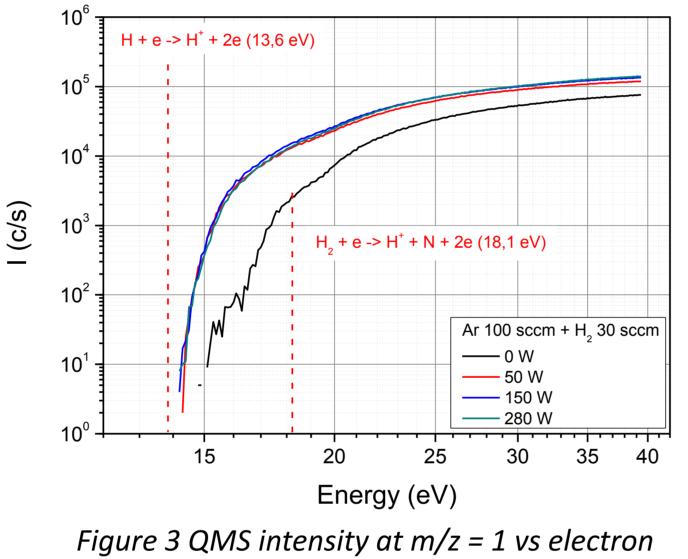
recombination coefficients of N or O atoms on silica, one can see a large amount of data which are widely spread.

We report results from our first measurements on the characterization by mass spectrometry of microwave remote plasmas used to create N and H atoms.

2. Dissociation rate determination

For Ar/N_2 plasma (and respectively Ar/H_2), QMS signal intensity at m/z = 14 (or 1) is the sum of the signal coming from the ionization of N (or H) atoms (produced in the plasma) and the dissociative ionization of N_2 (or H_2) molecules (see figure 2 and 3).





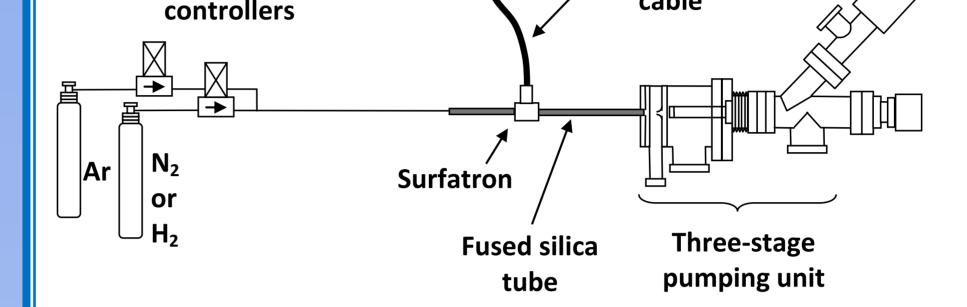
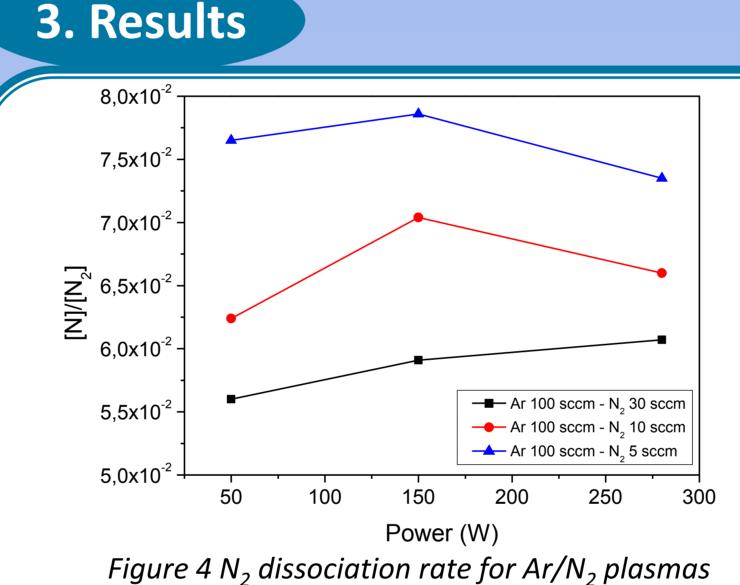
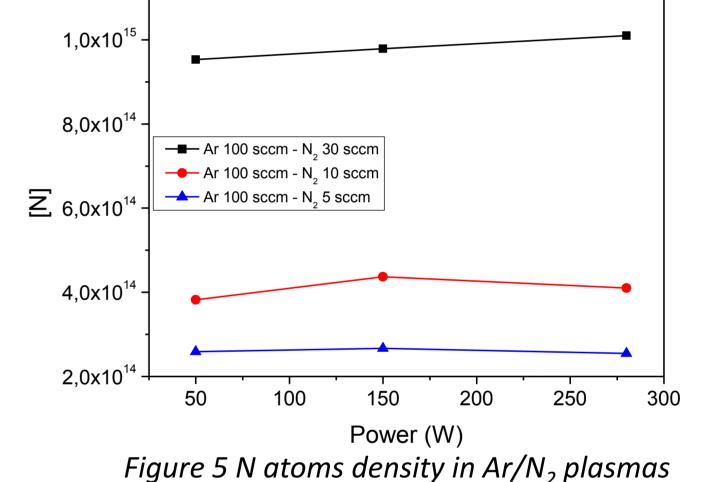


Figure 1 Experimental setup

neutral species from the postdischarges are collected and then positively ionized by electronic impact. For a X species, QMS signal intensity at the respective m/z ratio depends on electron energy ε and can be written:

 $I_X(\varepsilon) = A \times T_X \times \sigma_X(\varepsilon) \times \gamma \times [X] \times j_e$





energy for a Ar/N_2 plasma (100/30 sccm)

energy for a Ar/H_2 plasma (100/30 sccm)

As the threshold of these two processes are different, the signal intensity can easily be separated in the two components. This intensity can be expressed as follows:

 $Im_{/z=14}(\varepsilon = 20eV) = K \times \sigma_{N \to N^+}(\varepsilon = 20eV) \times [N]$ $I_{m_{/2}=14}(\varepsilon = 60eV) = K \times \left(\sigma_{N \to N^+}(\varepsilon = 60eV) \times [N] + \sigma_{N_2 \to N^+}(\varepsilon = 60eV) \times [N_2]\right)$

Knowing the values of the cross sections of these different processes [1-3], dissociation rate can be determined :

$$\frac{[N]}{[N_2]} = \frac{\frac{\sigma_{N_2 \to N^+}(\varepsilon = 60eV)}{\sigma_{N \to N^+}(\varepsilon = 20eV)}}{\frac{Im_{/_Z}=14}(\varepsilon = 60eV)}{\frac{Im_{/_Z}=14}(\varepsilon = 20eV)} - \frac{\sigma_{N \to N^+}(\varepsilon = 60eV)}{\sigma_{N \to N^+}(\varepsilon = 20eV)}$$

Similar expressions are obtained in the case of Ar/H_2 plasmas at m/z = 1.

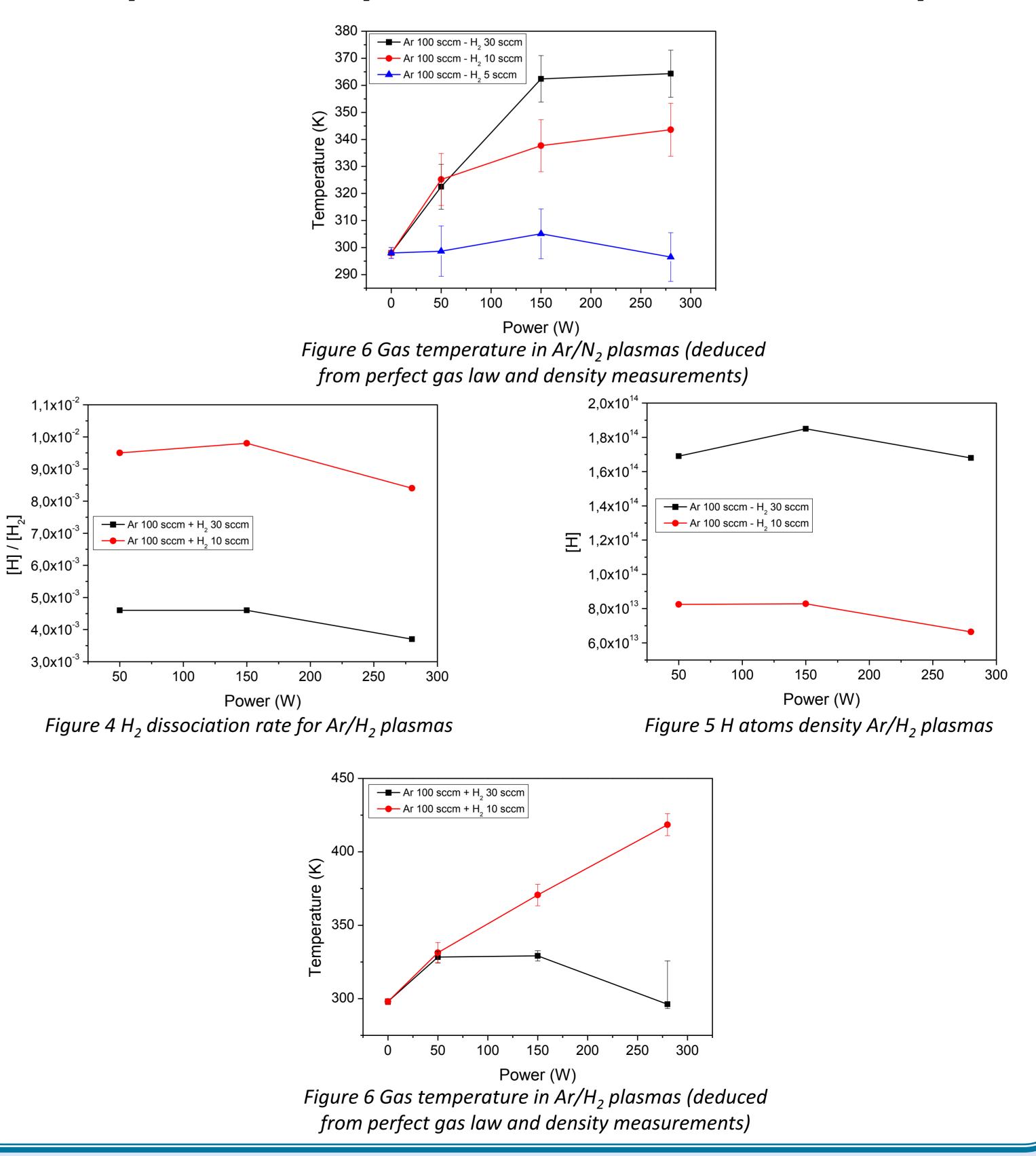
Conclusions & Perspectives

• N₂ and H₂ dissociation rate and N and H densities are in agreement with literature [4-6]

• Next steps :

Production of O and C atoms

• Study how atoms recombine on a surface put between the plasma source and the mass



spectrometer

References

[1] Y.K. Kim et al. NIST Electron-Impact Cross Sections for Ionization and Excitation. [online] 2004. [2] A. Crowe, J.W. McConkey J. Phys.B: Atom. Molec. Phys. 1973, Vol. 6, pp. 2108-2117. [3] **R.K. Janev, et al.** *Elementary Processes in Hydrogen-Helium Plasmas,* Springer, Berlin (1987). [4] J. Henriques et al. Vacuum 69 (2003) 177–181 [5] **A. Ricard et al.** *J. Phys. D* 27 (1994) 504 [6] W.G. Wand et al. Rapid Commun. Mass Spectrom. 19 (2005) 1159-1166